

DOCKET NO: 250340US0SRD DIV

IN THE UNITED STATES PATENT & TRADEMARK OFFICE

IN RE APPLICATION OF :
KOICHIRO INOMATA, ET AL. : ATTN: APPLICATION DIVISION
SERIAL NO: NEW APPLICATION :
FILED: HEREWITH :
FOR: MAGNETORESISTIVE ELEMENT :
AND MAGNETIC MEMORY
DEVICE

PRELIMINARY AMENDMENT

COMMISSIONER FOR PATENTS
ALEXANDRIA, VIRGINIA 22313

SIR:

Prior to examination on the merits, please amend the above-identified application as follows:

Amendments to the Specification begin on page 2 of this paper.

Amendments to the Claims are reflected in the listing of claims which begins on page 3 of this paper.

Discussion of the Amendment begins on page 6 of this paper.

Remarks begin on page 7 of this paper.